

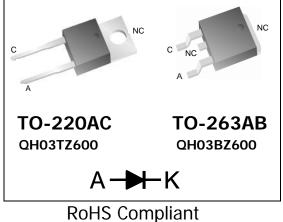
QH03TZ600, QH03BZ600 Qspeed[™] Family

600 V, 3 A H-Series PFC Diode

Product Summary

I _{F(AVG)}	3	А
V _{RRM}	600	V
Q _{RR} (Typ at 125 °C)	14.8	nC
I _{RRM} (Typ at 125 °C)	1.35	A
Softness t _B /t _A (Typ at 125 °C)	1.1	

Pin Assignment



Package uses Lead-free plating and Green mold compound. Halogen free per IEC 61249-2-21.

Absolute Maximum Ratings

General Description

This device has the lowest Q_{RR} of any 600 V silicon diode. Its recovery characteristics increase efficiency, reduce EMI and eliminate snubbers.

Applications

- Power Factor Correction (PFC) boost diode
- Motor drive circuits
- DC-AC Inverters

Features

- Low Q_{RR} , low I_{RRM} , low t_{RR}
- High dI_F/dt capable (1000 A / μs)
- Soft recovery

Benefits

- Increases efficiency
 - Eliminates need for snubber circuits
 - Reduces EMI filter component size & count
- Enables extremely fast switching

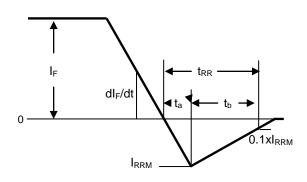
Absolute maximum ratings are the values beyond which the device may be damaged or have its useful life impaired. Functional operation under these conditions is not implied.

Symbol	Parameter	Conditions	Rating	Units
V _{RRM}	Peak repetitive reverse voltage	$T_{J} = 25 \ ^{\circ}C$	600	V
I _{F(AVG)}	Average forward current	$T_{J} = 150 \text{ °C}, T_{C} = 120 \text{ °C}$	3	А
I _{FSM}	Non-repetitive peak surge current	60 Hz, $\frac{1}{2}$ cycle, $T_c = 25 \text{ °C}$	35	А
I _{FSM}	Non-repetitive peak surge current	V_2 cycle of t = 28 μ s Sinusoid, T _C = 25 °C	350	А
ΤJ	Operating junction temperature range		-55 to 150	°C
T _{STG}	Storage temperature		-55 to 150	°C
	Lead soldering temperature	Leads at 1.6 mm from case, 10 sec	300	°C
VISOL	Isolation voltage (leads-to-tab)	AC, TO-220	2500	V
VISOL	Isolation voltage (leads-to-tab)	AC, TO-263	1500	V
P _D	Power dissipation	$T_{C} = 25 \ ^{\circ}C$	30.4	W

Symbol	Resistance from:	Conditions			Rating		Units	
R _{θJA}	Junction to ambient	TO-220 (only)				62	°C/W	
$R_{ ext{ ext{ ext{ ext{ ext{ ext{ ext{ ext$	Junction to case						4.1	°C/W
Electric	cal Specificatior	ns at $T_J = 25$ °C	C (unless	othe	rwis	se s	specif	ïed)
Symbol	Parameter	Conditions Min Typ Max					Units	
DC Chara	acteristics	•			<u>.</u>			
	Deveree everent	$V_{R} = 600 V$, $T_{J} = 25 °$	0	-	-		250	μA
I _R	Reverse current	$V_{R} = 600 \text{ V}, \text{ T}_{J} = 125 \text{ °C}$		- 0.		2	-	mA
VF	Forward voltage	$I_F = 3 \text{ A}, T_J = 25 \text{ °C}$		-	2.5	2	3.0	V
VF	Forward voltage	$I_F = 3 \text{ A}, T_J = 150 ^{\circ}\text{C}$		-	2.1	1	-	V
CJ	Junction capacitance	$V_{R} = 10 V$, 1 MHz		-	11		-	рF
Dynamic Characteristics								
	Reverse recovery time	$ dI/dt = 200 \ \text{A}/\mu \text{s} \\ V_R = 400 \ \text{V}, \ I_F = 3 \ \text{A} $	$T_J = 25 \ ^{\circ}C$	-	9.8	3	-	ns
t _{RR}	Reverse recovery time		$T_J = 125 \ ^\circ C$	-	16.	1	-	ns
0	Reverse recovery	$dI/dt = 200 A/\mu s$	$T_J = 25 \ ^\circ C$	-	5.8	3	10	nC
Q _{RR}	charge	$V_{R} = 400 V$, $I_{F} = 3 A$	$T_J = 125 \ ^\circ C$	-	14.	8	-	nC
	Maximum reverse	$dI/dt = 200 A/\mu s$	$T_J = 25 \ ^\circ C$	-	0.9	3	1.4	А
RRM	recovery current $V_R = 400 V$, $I_F = 3 A$	$V_{R} = 400 V, I_{F} = 3 A$	$T_J = 125 \ ^\circ C$	-	1.3	5	-	А
<u> </u>	S Softness factor = $\frac{t_B}{t_A}$ $\frac{dI/dt}{V_R} = 200 \text{ A/}\mu\text{s}$ $V_R = 400 \text{ V}, I_F = 3 \text{ A}$	$dI/dt = 200 A/\mu s$	$T_J = 25 \ ^\circ C$	-	0.9	2	-	
S		T _J = 125 °C	-	1.1	1	-		

Thermal Resistance

Note to component engineers: H-Series diodes employ Schottky technologies in their design and construction. Therefore, Component Engineers should plan their test setups to be similar to those for traditional Schottky test setups. (For additional details, see Application Note AN-300.)



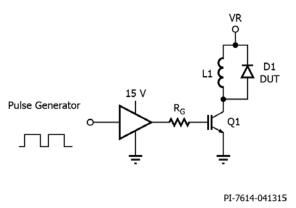
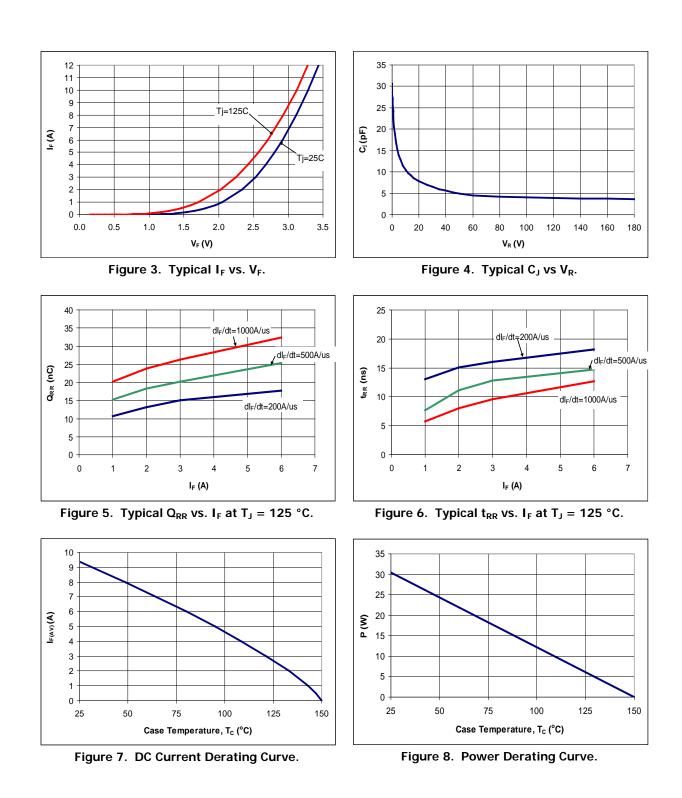


Figure 1. Reverse Recovery Definitions.









Electrical Specifications at $T_J = 25$ °C (unless otherwise specified)

3 Rev 1.3 11/15



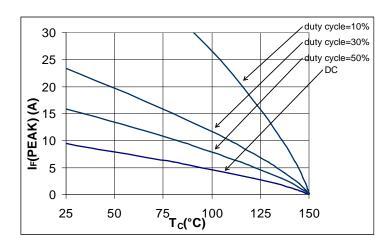


Figure 9. I_F (PEAK) vs. $T_{C_1} f = 70 \text{ kHz}$.

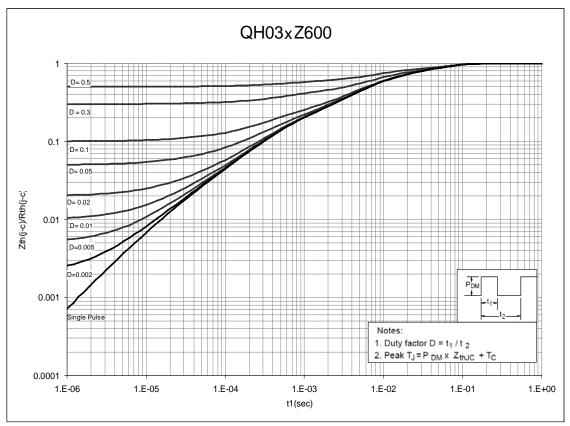


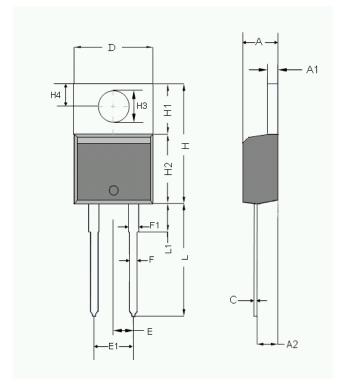
Figure 10. Normalized Maximum Transient Thermal Impedance.





Dimensional Outline Drawing

TO-220AC



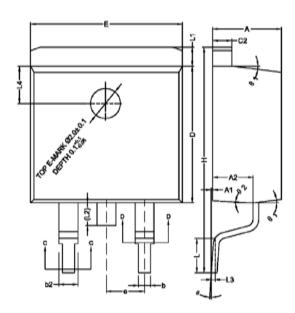
	Millimeters			
Dim	MIN	MAX		
Α	4.32	4.70		
A1	1.14	1.40		
A2	2.03	2.79		
С	0.34	0.610		
D	9.65	10.67		
E	2.49	2.59		
E1	4.98	5.18		
F	0.508	1.016		
F1	1.14	1.78		
н	14.71	16.51		
H1	5.84	6.795		
H2	8.40	9.00		
H3	3.53	3.96		
H4	2.54	3.05		
L	12.70	14.22		
L1	-	6.35		





Dimensional Outline Drawing

TO-263AB

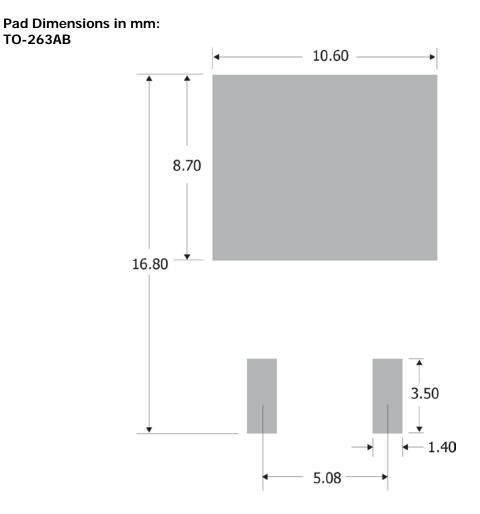


	Millimeters			
Dim	MIN	MAX		
А	4.40	4.70		
A1	0.00	0.25		
A2	2.59	2.79		
b	0.77	0.90		
b2	1.23	1.36		
c2	1.22	1.32		
D	9.05	9.25		
E	10.06	10.26		
е	2.54 BSC	2.54 BSC		
Н	14.70	15.50		
L	2.00	2.60		
L1	1.17	1.40		
L2	-	1.75		
L3	0.25 BSC	0.25 BSC		
L4	2.00 BSC	2.00 BSC		
Θ	0°	8°		
01	5°	9°		
02	1°	5°		

Mechanical Mounting Method	d Maximum Torque / Pressure specification		
Screw through hole in package tab	1 Newton Meter (nm) or 8.8 inch-pounds (lb-in)		
Clamp against package body	12.3 kilogram-force per square centimeter (kgf/cm ²) or 175 lbf/in ²		







Footprint and Solder Pad Dimensions

Soldering time and temperature: This product has been designed for use with high-temperature, lead-free solder. The component leads can be subjected to a maximum temperature of 300 °C, for up to 10 seconds. See Application Note AN-303, for more details.

Ordering Information

Part Number	Package	Packing
QH03TZ600	TO-220AB	50 units/tube
QH03BZ600	TO-263AB	800 units/reel

The information contained in this document is subject to change without notice.



QH03TZ600, QH03BZ600

Revision	Notes	Date
1.0	Released by Qspeed	01/10
1.1	Converted to Power Integrations Document	01/11
1.2	Added QH03BZ600	02/13
1.3	Updated with new Brand Style. Added footprint and solder pad dimension for TO-263AB package.	11/15





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